# **3.0 A Positive Voltage Regulators**

This family of fixed voltage regulators are monolithic integrated circuits capable of driving loads in excess of 3.0 A. These three-terminal regulators employ internal current limiting, thermal shutdown, and safe-area compensation. Devices are available with improved specifications, including a 2% output voltage tolerance, on AC-suffix 5.0 V, 12 V and 15 V device types.

Although designed primarily as a fixed voltage regulator, these devices can be used with external components to obtain adjustable voltages and currents. This series of devices can be used with a series–pass transistor to supply up to 15 A at the nominal output voltage.

- Output Current in Excess of 3.0 A
- Power Dissipation: 25 W
- No External Components Required
- Output Voltage Offered in 2% and 4% Tolerance\*
- Thermal Regulation is Specified
- Internal Thermal Overload Protection
- Internal Short Circuit Current Limiting
- Output Transistor Safe-Area Compensation
- Pb–Free Packages are Available

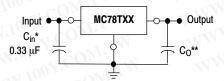


Figure 1. Simplified Application

A common ground is required between the input and the output voltages. The input voltage must remain typically 2.2 V above the output voltage even during the low point on the input ripple voltage.

XX these two digits of the type number indicate voltage.

- \* C<sub>in</sub> is required if regulator is located an appreciable distance from power supply filter. (See Applications Information for details.)
- \*\* C<sub>O</sub> is not needed for stability; however, it does improve transient response.

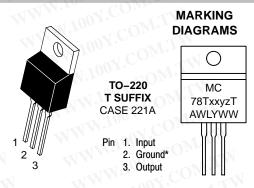
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# 3 A POSITIVE FIXED VOLTAGE REGULATORS



\*Heatsink surface is connected to Pin 2.



MC = Specific Device Code

- xx = Voltage Option
- y = "A" letter for precise 2% regulators, not used for standard 4% regulators.
- z = temperature range, "B" for wide temperature range, -40°C to +125°C, "C for standard temperature range, 0°C to +125°C.
- = Assembly Location
- WL= Wafer Lot
- Y = Year
- W = Work Week

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 10 of this data sheet.

#### **MAXIMUM RATINGS** (T<sub>A</sub> = +25°C, unless otherwise noted.)

Rating	Symbol	Value	Unit
Input Voltage (5.0 V – 12 V) (15 V)	VI	35 40	Vdc
Power Dissipation and Thermal Characteristics	ON.		
Plastic Package (Note 1) $T_A = +25^{\circ}C$	PD	Internally Limited	
Thermal Resistance, Junction–to–Air $T_{\rm C} = +25^{\circ}{\rm C}$	R <sub>θJA</sub> P <sub>D</sub>	65 Internally Limited	°C/W
Thermal Resistance, Junction-to-Case	R <sub>θJC</sub>	2.5	°C/W
Storage Junction Temperature	T <sub>stg</sub>	+150	°C
Operating Junction Temperature Range (MC78T00C, AC)	U.10UV.C	0 to +125	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Although power dissipation is internally limited, specifications apply only for  $P_0 \le P_{max}$ ,  $P_{max} = 25$  W.

**ELECTRICAL CHARACTERISTICS** (V<sub>in</sub> = 10 V, I<sub>O</sub> = 3.0 A, 0°C  $\leq$  T<sub>J</sub>  $\leq$  125°C, P<sub>O</sub>  $\leq$  P<sub>max</sub> (Note 2), unless otherwise noted.)

V.TOO. A. COMP.	V.CON		/IC78T05A	C	N	MC78T05	0	
Characteristics	Symbol	Min	Тур	Max	Min	Тур	Max	Unit
	Vo	4.9 4.8	5.0 5.0	5.1 5.2	4.8 4.75	5.0 5.0	5.2 5.25	Vdc
$ \begin{array}{l} \mbox{Line Regulation (Note 3)} \\ (7.2 \mbox{ Vdc} \leq V_{in} \leq 35 \mbox{ Vdc}, \mbox{ I}_{O} = 5.0 \mbox{ mA}, \mbox{ T}_{J} = +25^{\circ}\mbox{C}; \\ 7.2 \mbox{ Vdc} \leq V_{in} \leq 35 \mbox{ Vdc}, \mbox{ I}_{O} = 1.0 \mbox{ A}, \mbox{ T}_{J} = +25^{\circ}\mbox{C}; \\ 8.0 \mbox{ Vdc} \leq V_{in} \leq 12 \mbox{ Vdc}, \mbox{ I}_{O} = 3.0 \mbox{ A}, \mbox{ T}_{J} = +25^{\circ}\mbox{C}; \\ 7.5 \mbox{ Vdc} \leq V_{in} \leq 20 \mbox{ Vdc}, \mbox{ I}_{O} = 1.0 \mbox{ A}) \end{array} $	Reg <sub>line</sub>	1.COM	3.0	25	M.M.	3.0	25	mV
Load Regulation (Note 3) (5.0 mA $\le$ I <sub>O</sub> $\le$ 3.0 A, T <sub>J</sub> = +25°C) (5.0 mA $\le$ I <sub>O</sub> $\le$ 3.0 A)	Reg <sub>load</sub>	100X.	10 15	30 80	_ {	10 15	30 80	mV
Thermal Regulation (Pulse = 10 ms, P = 20 W, $T_A = +25^{\circ}C$ )	Reg <sub>therm</sub>	N.100	0.001	0.01	-	0.002	0.03	%V <sub>O</sub> /W
Quiescent Current (5.0 mA $\leq I_O \leq 3.0$ A, T <sub>J</sub> = +25°C) (5.0 mA $\leq I_O \leq 3.0$ A)	Ι <sub>Β</sub>	(N.10 N.41.1	3.5 4.0	5.0 6.0	N -	3.5 4.0	5.0 6.0	mA
$ \begin{array}{l} \mbox{Quiescent Current Change} \\ (7.2 \mbox{ Vdc} \leq \mbox{V}_{in} \leq 35 \mbox{ Vdc}, \mbox{ I}_{O} = 5.0 \mbox{ mA}, \mbox{ T}_{J} = +25^{\circ}\mbox{C}; \\ 5.0 \mbox{ mA} \leq \mbox{ I}_{O} \leq 3.0 \mbox{ A}, \mbox{ T}_{J} = +25^{\circ}\mbox{C}; \\ 7.5 \mbox{ Vdc} \leq \mbox{ V}_{in} \leq 20 \mbox{ Vdc}, \mbox{ I}_{O} = 1.0 \mbox{ A}) \end{array} $	ΔI <sub>B</sub>	NMA NMA	0.3		LIN III	0.3	1.0	mA
Ripple Rejection (8.0 Vdc $\leq$ V <sub>in</sub> $\leq$ 18 Vdc, f = 120 Hz, I <sub>O</sub> = 2.0 A, T <sub>J</sub> = 25°C)	RR	62	75	0 <u>7.</u> CO	62	75	M.M.	dB
Dropout Voltage (I <sub>O</sub> = 3.0 A, $T_J$ = +25°C)	V <sub>in</sub> –V <sub>O</sub>	-74	2.2	2.5	·0 <sup>4</sup> 0:	2.2	2.5	Vdc
Output Noise Voltage (10 Hz $\leq$ f $\leq$ 100 kHz, T <sub>J</sub> = +25°C)	Vn	-	10	1001.	COM	10	-	μV/V <sub>O</sub>
Output Resistance (f = 1.0 kHz)	Ro	_	2.0	N	V.COx	20	-	mΩ

 Although power dissipation is internally limited, specifications apply only for P<sub>O</sub> ≤ P<sub>max</sub>, P<sub>max</sub> = 25 W.
 Line and load regulation are specified at constant junction temperature. Changes in V<sub>O</sub> due to heating effects must be taken into account separately.

Pulse testing with low duty cycle is used.

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ELECTRICAL CHARACTERISTICS (Vin = 10 V, IO = 3.0	A, $0^{\circ}C \le T_{J} \le 125^{\circ}C$ , $P_{O} \le P_{max}$ (Note 2), unless otherwise noted.)
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WWW. SON.COM TY	· · · ·	MC78T05AC			MC78T05C			
Characteristics	Symbol	Min	Тур	Max	Min	Тур	Max	Unit
Short Circuit Current Limit ( $V_{in} = 35 \text{ Vdc}, T_J = +25^{\circ}\text{C}$ )	Isc Isc	44	1.5	N.CO	M.TV	1.5	-	A
Peak Output Current ( $T_J = +25^{\circ}C$ )	I <sub>max</sub>	-71	5.0	007.0	T.Iro	5.0	-	А
Average Temperature Coefficient of Output Voltage $(I_O = 5.0 \text{ mA})$	TCVO	- 1	0.2	100-Y.C	coM.	0.2	-	mV/°C

 Although power dissipation is internally limited, specifications apply only for P<sub>O</sub> ≤ P<sub>max</sub>, P<sub>max</sub> = 25 W.
 Line and load regulation are specified at constant junction temperature. Changes in V<sub>O</sub> due to heating effects must be taken into account separately.

Pulse testing with low duty cycle is used.

#### $\textbf{ELECTRICAL CHARACTERISTICS} ~ (V_{in} = 13 ~ V, ~ I_O = 3.0 ~ A, ~ 0^{\circ}C \leq T_J \leq 125^{\circ}C, ~ P_O \leq P_{max} ~ (Note~4), ~ unless ~ otherwise ~ noted.)$

	WWW	.10-			
Characteristics	Symbol	Min	Тур	Мах	Unit
Output Voltage (5.0 mA $\le I_O \le 3.0$ A, T <sub>J</sub> = +25°C) (5.0 mA $\le I_O \le 3.0$ A; 5.0 mA $\le I_O \le 2.0$ A, 10.4 Vdc $\le V_{in} \le 23$ Vdc)	Vo	7.7 7.6	8.0 8.0	8.3 8.4	Vdc
$ \begin{array}{l} \text{Line Regulation (Note 5)} \\ (10.3 \ \text{Vdc} \leq \text{V}_{in} \leq 35 \ \text{Vdc}, \ \text{I}_{O} = 5.0 \ \text{mA}, \ \text{T}_{J} = +25^{\circ}\text{C} \\ 10.3 \ \text{Vdc} \leq \text{V}_{in} \leq 35 \ \text{Vdc}, \ \text{I}_{O} = 1.0 \ \text{A}, \ \text{T}_{J} = +25^{\circ}\text{C} \\ 11 \ \text{Vdc} \leq \text{V}_{in} \leq 17 \ \text{Vdc}, \ \text{I}_{O} = 3.0 \ \text{A}, \ \text{T}_{J} = +25^{\circ}\text{C} \\ 10.7 \ \text{Vdc} \leq \text{V}_{in} \leq 23 \ \text{Vdc}, \ \text{I}_{O} = 1.0 \ \text{A} ) \end{array} $	Reg <sub>line</sub>	NWN NWN	4.0	35	mV
Load Regulation (Note 5) (5.0 mA $\le$ I <sub>O</sub> $\le$ 3.0 A, T <sub>J</sub> = +25°C) (5.0 mA $\le$ I <sub>O</sub> $\le$ 3.0 A)	Reg <sub>load</sub>	4	10 15	30 80	mV
Thermal Regulation (Pulse = 10 ms, P = 20 W, $T_A = +25^{\circ}C$ )	Reg <sub>therm</sub>	- 1	0.002	0.03	%V <sub>O</sub> /W
	I <sub>B</sub>	-	3.5 4.0	5.0 6.0	CCmA COM
Quiescent Current Change (10.3 Vdc $\leq V_{in} \leq 35$ Vdc, I <sub>O</sub> = 5.0 mA, T <sub>J</sub> = +25°C; 5.0 mA $\leq I_O \leq 3.0$ A, T <sub>J</sub> = +25°C; 10.7 Vdc $\leq V_{in} \leq 23$ Vdc, I <sub>O</sub> = 1.0 A)	Δl <sub>B</sub>	- 7	0.3	1.0	mA
Ripple Rejection (11 Vdc $\leq$ V <sub>in</sub> $\leq$ 21 Vdc, f = 120 Hz, I <sub>O</sub> = 2.0 A, T <sub>J</sub> = 25°C)	RR	60	71 🔨	MMM.	dB
Dropout Voltage ( $I_0 = 3.0 \text{ A}, T_J = +25^{\circ}\text{C}$ )	V <sub>in</sub> –V <sub>O</sub>		2.2	2.5	Vdc
Output Noise Voltage (10 Hz ≤ f ≤ 100 kHz, T <sub>J</sub> = +25°C)	Vn	$T_{M}$	10	WW.	μV/V <sub>O</sub>
Output Resistance (f = 1.0 kHz)	R <sub>O</sub>	<u>) 17</u>	2.0	717	mΩ
Short Circuit Current Limit (V <sub>in</sub> = 35 Vdc, T <sub>J</sub> = +25°C)	I <sub>SC</sub>	0 <u>0</u> 7.,	1.5	- 41	A
Peak Output Current ( $T_J = +25^{\circ}C$ )	I <sub>max</sub>		5.0	- 1	А
Average Temperature Coefficient of Output Voltage (I <sub>O</sub> = 5.0 mA)	TCVO	1.0205	0.3	-	mV/°C

4. Although power dissipation is internally limited, specifications apply only for P<sub>O</sub> ≤ P<sub>max</sub>, P<sub>max</sub> = 25 W.
5. Line and load regulation are specified at constant junction temperature. Changes in V<sub>O</sub> due to heating effects must be taken into account separately.

Pulse testing with low duty cycle is used.

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<b>ELECTRICAL CHARACTERISTICS</b> ( $V_{in}$ = 17 V, $I_O$ = 3.0 A, $0^{\circ}C \le T_J \le 125^{\circ}C$ , $P_O \le P_{max}$ (Note 6), unless otherwise noted.)

WWW. ON.COM TW	N N	MC78T12AC			MC78T12C			
Characteristics	Symbol	Min	Тур	Max	Min	Тур	Max	Unit
	Vo	11.75 11.5	12 12	12.25 12.5	11.5 11.4	12 12	12.5 12.6	Vdc
$ \begin{array}{l} \mbox{Line Regulation (Note 7)} \\ (14.5 \mbox{ Vdc} \leq V_{in} \leq 35 \mbox{ Vdc}, \mbox{ I}_{O} = 5.0 \mbox{ mA}, \mbox{ T}_{J} = +25^{\circ}\mbox{C}; \\ 14.5 \mbox{ Vdc} \leq V_{in} \leq 35 \mbox{ Vdc}, \mbox{ I}_{O} = 1.0 \mbox{ A}, \mbox{ T}_{J} = +25^{\circ}\mbox{C}; \\ 16 \mbox{ Vdc} \leq V_{in} \leq 22 \mbox{ Vdc}, \mbox{ I}_{O} = 3.0 \mbox{ A}, \mbox{ T}_{J} = +25^{\circ}\mbox{C}; \\ 14.9 \mbox{ Vdc} \leq V_{in} \leq 27 \mbox{ Vdc}, \mbox{ I}_{O} = 1.0 \mbox{ A}) \end{array} $	Reg <sub>line</sub>	- 4	6.0	45	OMIT COMI COM	6.0	45	mV
Load Regulation (Note 7) (5.0 mA $\le$ I <sub>O</sub> $\le$ 3.0 A, T <sub>J</sub> = +25°C) (5.0 mA $\le$ I <sub>O</sub> $\le$ 3.0 A)	Reg <sub>load</sub>	-	10 15	30 80	V.CON	10 15	30 80	mV
Thermal Regulation (Pulse = 10 ms, P = 20 W, $T_A$ = +25°C)	Reg <sub>therm</sub>	- 7 2	0.001	0.01	01: 01:00	0.002	0.03	%V <sub>O</sub> /W
Quiescent Current (5.0 mA $\leq I_O \leq 3.0$ A, $T_J = +25^{\circ}C$ ) (5.0 mA $\leq I_O \leq 3.0$ A)	V.COM	NT.	3.5 4.0	5.0 6.0	10 <u>0</u> ¥.0	3.5 4.0	5.0 6.0	mA
$ \begin{array}{l} \mbox{Quiescent Current Change} \\ (14.5 \mbox{ Vdc} \leq \mbox{V}_{in} \leq 35 \mbox{ Vdc}, \mbox{ I}_{O} = 5.0 \mbox{ mA}, \mbox{ T}_{J} = +25^{\circ}\mbox{C}; \\ 5.0 \mbox{ mA} \leq \mbox{ I}_{O} \leq 3.0 \mbox{ A}, \mbox{ T}_{J} = +25^{\circ}\mbox{C}; \\ 14.9 \mbox{ Vdc} \leq \mbox{ V}_{in} \leq 27 \mbox{ Vdc}, \mbox{ I}_{O} = 1.0 \mbox{ A}) \end{array} $	Δl <sub>B</sub>	M.TW	0.3	1.0	W.100	0.3	1.0	mA
	RR	57	67	4 <u>-</u> 7	57	67	0 <u>N</u> . 1.1 0.1	dB
Dropout Voltage ( $I_0 = 3.0 \text{ A}, T_J = +25^{\circ}\text{C}$ )	V <sub>in</sub> – V <sub>O</sub>		2.2	2.5		2.2	2.5	Vdc
Output Noise Voltage (10 Hz $\leq$ f $\leq$ 100 kHz, T <sub>J</sub> = +25°C)	Vn	<u>4.00</u>	10	-	M.M.	10	V.CO	μV/V <sub>O</sub>
Output Resistance (f = 1.0 kHz)	Ro	-7 C	2.0	- IA	707	20	V.CC	mΩ
Short Circuit Current Limit ( $V_{in} = 35 \text{ Vdc}, T_J = +25^{\circ}\text{C}$ )	I <sub>SC</sub>	100 <u>2</u> .	1.5	N.	- 1	1.5	00 <u>7</u> .C	A
Peak Output Current (T <sub>J</sub> = +25°C)	I <sub>max</sub>	100	5.0	FT		5.0	NOY.	Α
Average Temperature Coefficient of Output Voltage (I <sub>O</sub> = 5.0 mA)	TCVO	N.100	0.5	WT.I		0.5	1.1005	mV/°C

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6. Although power dissipation is internally limited, specifications apply only for  $P_0 \le P_{max}$ ,  $P_{max} = 25$  W. 7. Line and load regulation are specified at constant junction temperature. Changes in V<sub>0</sub> due to heating effects must be taken into account WW.100Y.COM.TW separately.

Pulse testing with low duty cycle is used. WWW.100Y.COM!

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		M	C78T15A	С	W	MC78T150		
Characteristics	Symbol	Min	Тур	Max	Min	Тур	Max	Unit
	Vo	14.7 14.4	15 15	15.3 15.6	14.4 14.25	15 15	15.6 15.75	Vdc
$ \begin{array}{l} \text{Line Regulation (Note 9)} \\ (17.6 \ \text{Vdc} \leq V_{in} \leq 40 \ \text{Vdc}, \ I_O = 5.0 \ \text{mA}, \ T_J = +25^\circ\text{C}; \\ 17.6 \ \text{Vdc} \leq V_{in} \leq 40 \ \text{Vdc}, \ I_O = 1.0 \ \text{A}, \ T_J = +25^\circ\text{C}; \\ 20 \ \text{Vdc} \leq V_{in} \leq 26 \ \text{Vdc}, \ I_O = 3.0 \ \text{A}, \ T_J = +25^\circ\text{C}; \\ 18 \ \text{Vdc} \leq V_{in} \leq 30 \ \text{Vdc}, \ I_O = 1.0 \ \text{A} ) \end{array} $	Reg <sub>line</sub>	- 4	7.5	55	ONI.T COM. <sup>T</sup> COM	7.5	55	mV
Load Regulation (Note 9) (5.0 mA $\le$ I <sub>O</sub> $\le$ 3.0 A, T <sub>J</sub> = +25°C) (5.0 mA $\le$ I <sub>O</sub> $\le$ 3.0 A)	Reg <sub>load</sub>	- 1	10 15	30 80	<u>x.c</u> 01	10 15	30 80	mV
Thermal Regulation (Pulse = 10 ms, P = 20 W, $T_A = +25^{\circ}C$ )	Reg <sub>therm</sub>	N I	0.001	0.01	00 <u>7</u> .C	0.002	0.03	%V <sub>O</sub> /W
Quiescent Current (5.0 mA $\le$ I <sub>O</sub> $\le$ 3.0 A, T <sub>J</sub> = +25°C) (5.0 mA $\le$ I <sub>O</sub> $\le$ 3.0 A)	S.G <sub>B</sub>	T.T.W	3.5 4.0	5.0 6.0	.1001.	3.5 4.0	5.0 6.0	mA
	Δl <sub>B</sub>	OM.T	0.3	1.0	N.100 M.100	0.3	1.0	mA
	RR	55	65	- 1	55	65	CO <sub>W</sub> .	dB
Dropout Voltage ( $I_O = 3.0 \text{ A}, T_J = +25^{\circ}\text{C}$ )	V <sub>in</sub> -V <sub>O</sub>	< CO <sup>2</sup>	2.2	2.5	W	2.2	2.5	Vdc
Output Noise Voltage (10 Hz $\leq$ f $\leq$ 100 kHz, T <sub>J</sub> = +25°C)	Vn	ox.co	10	<u>-</u> ۷	MM	10	Y.CON	μV/V <sub>O</sub>
Output Resistance (f = 1.0 kHz)	R <sub>O</sub>	ONT.C	2.0	- 12	-17	20	01-CC	mΩ
Short Circuit Current Limit (V <sub>in</sub> = 40 Vdc, T <sub>J</sub> = +25°C)	Isc	.100Y.	1.0	LM <del>.</del>	- 1	1.0	007.C	A
Peak Output Current (T <sub>J</sub> = +25°C)	I <sub>max</sub>	N 1 <del>0</del> 0X	5.0	T.	-	5.0	1002.	Α
Average Temperature Coefficient of Output Voltage $(I_O = 5.0 \text{ mA})$	TCVO	W. <u>1</u> 00	0.6	N.FW	-	0.6	N.1907	mV/°C

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8. Although power dissipation is internally limited, specifications apply only for  $P_0 \le P_{max}$ ,  $P_{max} = 25$  W. 9. Line and load regulation are specified at constant junction temperature. Changes in V<sub>0</sub> due to heating effects must be taken into account .100X.CO separately.

Pulse testing with low duty cycle is used.

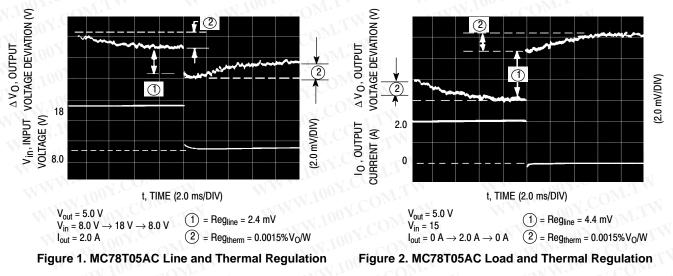
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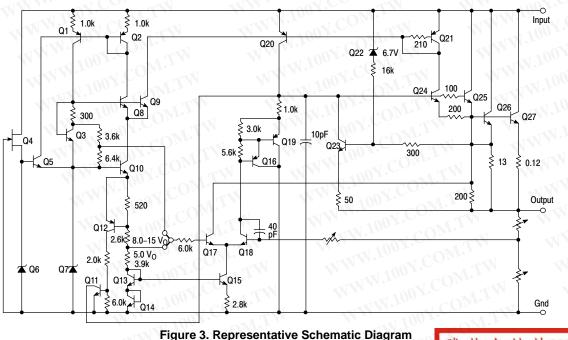
#### **VOLTAGE REGULATOR PERFORMANCE**

The performance of a voltage regulator is specified by its immunity to changes in load, input voltage, power dissipation, and temperature. Line and load regulation are tested with a pulse of short duration (< 100  $\mu$ s) and are strictly a function of electrical gain. However, pulse widths of longer duration (> 1.0 ms) are sufficient to affect temperature gradients across the die. These temperature gradients can cause a change in the output voltage, in addition to changes caused by line and load regulation. Longer pulse widths and thermal gradients make it desirable to specify thermal regulation.

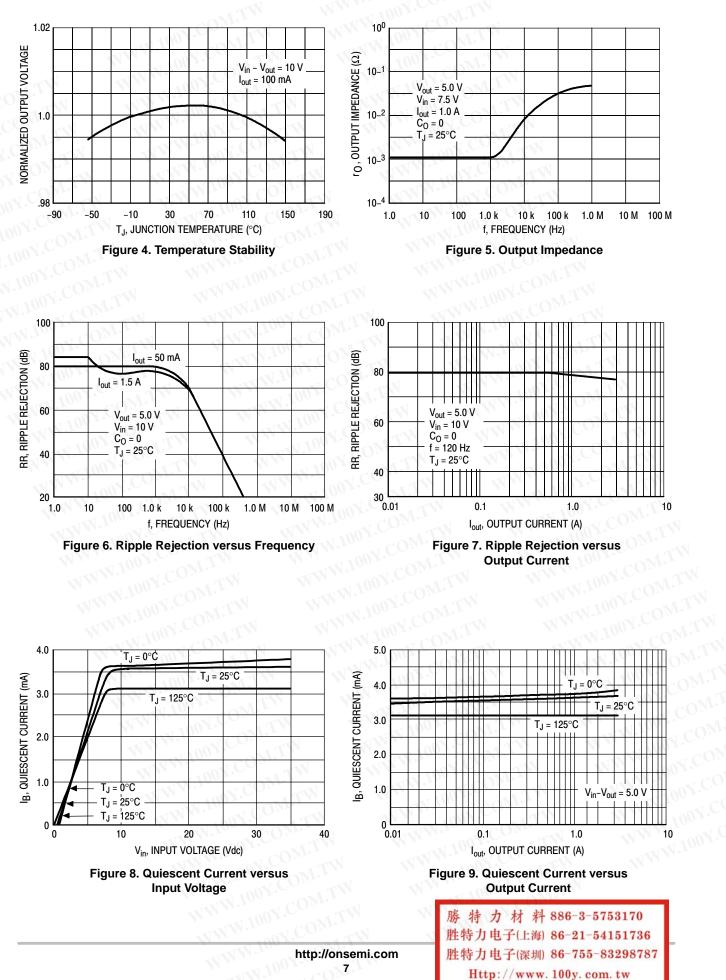
Thermal regulation is defined as the change in output voltage caused by a change in dissipated power for a specified time, and is expressed as a percentage output voltage change per watt. The change in dissipated power can be caused by a change in either the input voltage or the load current. Thermal regulation is a function of IC layout and die attach techniques, and usually occurs within 10 ms of a change in power dissipation. After 10 ms, additional changes in the output voltage are due to the temperature coefficient of the device.

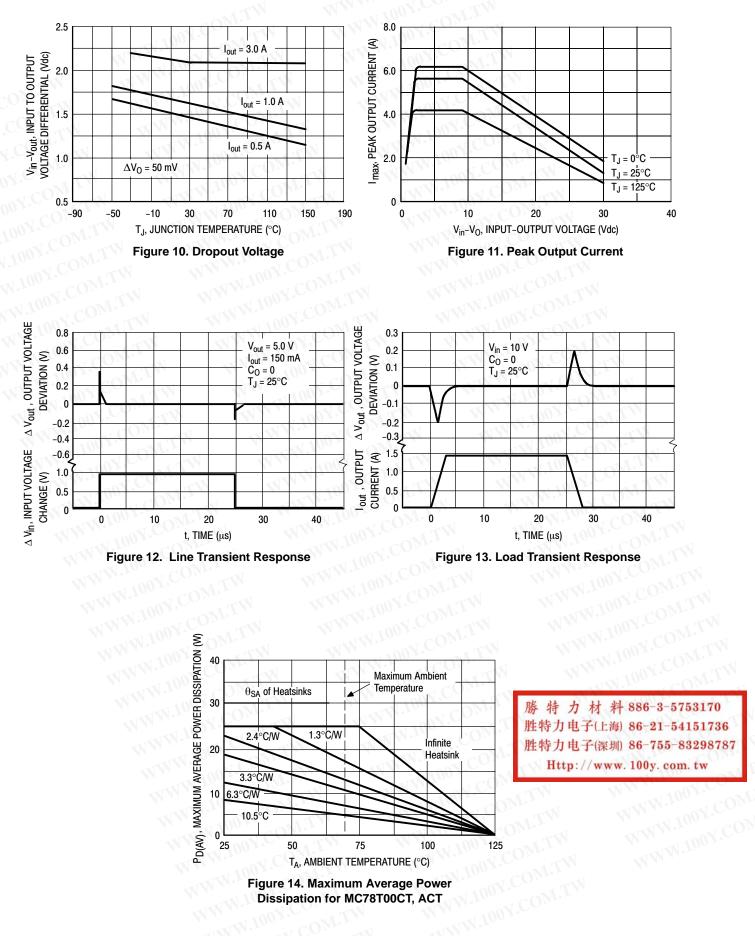
Figure 1 shows the line and thermal regulation response of a typical MC78T05AC to a 20 W input pulse. The variation of the output voltage due to line regulation is labeled ① and the thermal regulation component is labeled ②. Figure 2 shows the load and thermal regulation response of a typical MC78T05AC to a 20 W load pulse. The output voltage variation due to load regulation is labeled ① and the thermal regulation component is labeled ①.





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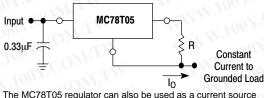


#### APPLICATIONS INFORMATION

#### **Design Considerations**

The MC78T00 Series of fixed voltage regulators are designed with Thermal Overload Protection that shuts down the circuit when subjected to an excessive power overload condition, Internal Short Circuit Protection that limits the maximum current the circuit will pass, and Output Transistor Safe–Area Compensation that reduces the output short circuit current as the voltage across the pass transistor is increased.

In many low current applications, compensation capacitors are not required. However, it is recommended that the regulator input be bypassed with a capacitor if the



when connected as above. In order to minimize dissipation the MC78T05 is chosen in this application. Resistor R determines the current as follows:

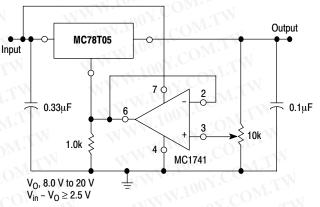
$$I_0 = \frac{5.0 \text{ V}}{\text{R}} + I_{\text{B}}$$

 $\Delta I_B \cong 0.7$  mA over line, load and Temperature changes  $I_B \cong 3.5$  mA

For example, a 2.0 A current source would require R to be a 2.5  $\Omega$ , 10 W resistor and the output voltage compliance would be the input voltage less 7.0 V.

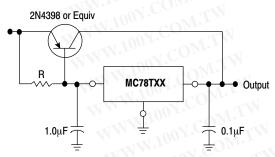
#### Figure 15. Current Regulator

regulator is connected to the power supply filter with long wire lengths, or if the output load capacitance is large. An input bypass capacitor should be selected to provide good high frequency characteristics to insure stable operation under all load conditions. A 0.33  $\mu$ F or larger tantalum, mylar, or other capacitor having low internal impedance at high frequencies should be chosen. The bypass capacitor should be mounted with the shortest possible leads directly across the regulator's input terminals. Normally good construction techniques should be used to minimize ground loops and lead resistance drops since the regulator has no external sense lead.



The addition of an operational amplifier allows adjustment to higher or intermediate values while retaining regulation characteristics. The minimum voltage obtainable with this arrangement is 3.0 V greater than the regulator voltage.

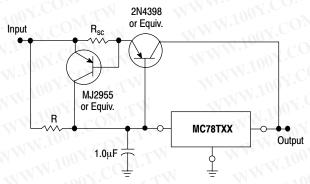
#### Figure 16. Adjustable Output Regulator





The MC78T00 series can be current boosted with a PNP transistor. The 2N4398 provides current to 15 A. Resistor R in conjunction with the V<sub>BE</sub> of the PNP determines when the pass transistor begins conducting; this circuit is not short circuit proof. Input-output differential voltage minimum is increased by the V<sub>BE</sub> of the pass transistor.

#### Figure 17. Current Boost Regulator

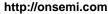


XX = 2 digits of type number indicating voltage.

The circuit of Figure 17 can be modified to provide supply protection against short circuits by adding a short circuit sense resistor,  $R_{SC}$ , and an additional PNP transistor. The current sensing PNP must be able to handle the short circuit current of the three-terminal regulator. Therefore, an eight-ampere power transistor is specified.

Figure 18. Current Boost With Short Circuit Protection

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# MC78T00 Series WWW.100Y.

Device	V <sub>O</sub> Tol.	Nominal Output Voltage	Operating Temperature Range	Package	Shipping <sup>†</sup>
MC78T05ABT	2%*	CONT.IN	$T_J = -40^{\circ}C TO + 125^{\circ}C$	TO-220	50 Units / Rail
MC78T05ACT	2%*	M.COM.TW	T <sub>J</sub> = 0°C TO +125°C	TO-220	50 Units / Rail
MC78T05ACTG	2%*	N.COM.TW	T <sub>J</sub> = 0°C TO +125°C	TO-220 (Pb-Free)	50 Units / Rail
MC78T05BT	4%	POL. COM.T	$T_J = -40^{\circ}C TO + 125^{\circ}C$	TO-220	50 Units / Rail
MC78T05BTG	4%	5.0 V	$T_{\rm J} = -40^{\circ}{\rm C} \text{ TO } +125^{\circ}{\rm C}$	TO–220 (Pb–Free)	50 Units / Tubes
MC78T05CD2T	4%	N.100 X.COM	T <sub>J</sub> = 0°C TO +125°C	D <sup>2</sup> PAK-3	50 Units / Rail
MC78T05CD2TR4	4%	IN.100 L. COM	T <sub>J</sub> = 0°C TO +125°C	D <sup>2</sup> PAK-3	800 / Tape & Ree
MC78T05CT	4%	W.1001.CO	T <sub>J</sub> = 0°C TO +125°C	TO-220	50 Units / Rail
MC78T05CTG	4%	WW.100Y.CO	T <sub>J</sub> = 0°C TO +125°C	TO–220 (Pb–Free)	50 Units / Rail
MC78T08CT	4%	8.0 V	$T_J = 0^{\circ}C TO + 125^{\circ}C$	TO-220	50 Units / Rail
MC78T12ACT	2%*	WW.100	T <sub>J</sub> = 0°C TO +125°C	TO-220	50 Units / Rail
MC78T12BT	4%	12 V	$T_J = -40^{\circ}C \text{ TO } +125^{\circ}C$	TO-220	50 Units / Rail
MC78T12CT	4%	WWW.100	T <sub>J</sub> = 0°C TO +125°C	TO-220	50 Units / Rail
MC78T15ABT	2%*	WW 100	T <sub>J</sub> = -40°C TO +125°C	TO-220	50 Units / Rail
MC78T15ACT	2%*	15 V	T <sub>J</sub> = 0°C TO +125°C	TO-220	50 Units / Rail
MC78T15CT	4%	NWW.1	T <sub>.1</sub> = 0°C TO +125°C	TO-220	50 Units / Rail

NOTE: Automotive temperature range selections are available with special test conditions and additional tests. Contact your local ON Semiconductor sales office for information.

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. WWW.100Y.

\*2% regulators available in 5.0 V, 12 V and 15 V devices.

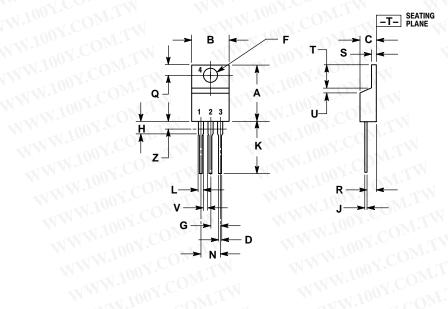


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TO-220 T SUFFIX CASE 221A-09 ISSUE AA



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		HES	MILLIMETERS				
DIM	MIN	MAX	MIN	MAX			
Α	0.570	0.620	14.48	15.75			
В	0.380	0.405	9.66	10.28			
С	0.160	0.190	4.07	4.82			
D	0.025	0.035	0.64	0.88			
F	0.142	0.147	3.61	3.73			
G	0.095	0.105	2.42	2.66			
Н	0.110	0.155	2.80	3.93			
J	0.018	0.025	0.46	0.64			
K	0.500	0.562	12.70	14.27			
L	0.045	0.060	1.15	1.52			
Ν	0.190	0.210	4.83	5.33			
Q	0.100	0.120	2.54	3.04			
R	0.080	0.110	2.04	2.79			
S	0.045	0.055	1.15	1.39			
T	0.235	0.255	5.97	6.47			
U	0.000	0.050	0.00	1.27			
۷	0.045		1.15	- ( <u></u> _			
Ζ		0.080	· · · ·	2.04			

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1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.

NOTES:

2.

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#### PACKAGE DIMENSIONS

D<sup>2</sup>PAK-3 CASE 936-03 ISSUE B

NOTES:

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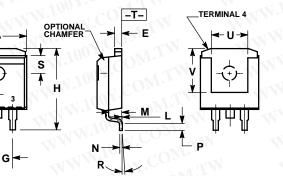
2. CONTROLLING DIMENSION: INCH.

3. TAB CONTOUR OPTIONAL WITHIN DIMENSIONS A AND K.

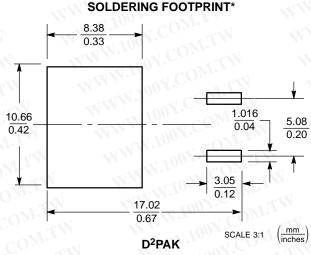
 A. DIMENSIONS U AND V ESTABLISH A MINIMUM MOUNTING SURFACE FOR TERMINAL 4.
 DIMENSIONS A AND B DO NOT INCLUDE MOLE

LIMENSIONS A AND BO NOT INCLUDE MOLD FLASH OR GATE PROTRUSIONS. MOLD FLASH AND GATE PROTRUSIONS NOT TO EXCEED 0.025 (0.635) MAXIMUM.

	INC	HES	MILLI	<b>NETERS</b>		
DIM	MIN	MAX	MIN	MAX		
A	0.386	0.403	9.804	10.236		
В	0.356	0.368	9.042	9.347		
C	0.170	0.180	4.318	4.572		
D	0.026	0.036	0.660	0.914		
Е	0.045	0.055	1.143	1.397		
F	0.051	I REF	1.29	5 REF		
G	0.100	) BSC	2.54	) BSC		
H	0.539	0.579	13.691	14.707		
J	0.125	0.125 MAX		3.175 MAX		
K	0.050	) REF	1.270 REF			
Lo	0.000	0.010	0.000	0.254		
Μ	0.088	0.102	2.235	2.591		
Ν	0.018	0.026	0.457	0.660		
P	0.058	0.078	1.473	1.981		
R	5°	REF	5°	REF		
S	0.116	6 REF	2.94	6 REF		
U	0.20	0 MIN	5.08	0 MIN		
۷	0.25	0 MIN	6.350 MIN			







\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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